### INTEGRATED CIRCUITS

## DATA SHEET

# **74LV393**Dual 4-bit binary ripple counter

Product specification Supersedes data of 1997 Mar 04 IC24 Data Handbook





### **Dual 4-bit binary ripple counter**

74LV393

#### **FEATURES**

- Optimized for Low Voltage applications: 1.0 to 3.6V
- Accepts TTL input levels between V<sub>CC</sub> = 2.7V and V<sub>CC</sub> = 3.6V
- Typical V<sub>OLP</sub> (output ground bounce) < 0.8V @ V<sub>CC</sub> = 3.3V,  $T_{amb} = 25^{\circ}C$
- Typical V<sub>OHV</sub> (output V<sub>OH</sub> undershoot) > 2V @ V<sub>CC</sub> = 3.3V,  $T_{amb} = 25^{\circ}C$
- Two 4-bit binary counters with individual clocks
- Divide-by any binary module up to 28 in one package
- Two master resets to clear each 4-bit counter individually
- Output capability: standard
- I<sub>CC</sub> category: MSI

#### DESCRIPTION

The 74LV393 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT393.

The 74LV393 is a dual 4-bit binary ripple counter with separate clocks (1CP, 2CP) and master reset (1MR, 2MR) inputs to each

The operation of each half of the "393" is the same as the "93" except no external clock connections are required. The counters are triggered by a HIGH-to-LOW transition of the clock inputs. The counter outputs are internally connected to provide clock inputs to succeeding stages. The outputs of the ripple counter do not change synchronously and should not be used for high-speed address decoding.

The master resets are active-HIGH asynchronous inputs to each 4-bit counter identified by the "1" and "2" in the pin description.

A HIGH level on the nMR input overrides the clock and sets the outputs LOW.

### **QUICK REFERENCE DATA**

GND = 0V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

SYMBOL	PARAMETER  Propagation delay nCP to nQ0 nQ to nQn+1 nMR to nQn  Maximum clock frequency  Input capacitance	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	nCP to nQ <sub>0</sub> nQ to nQn+1	C <sub>L</sub> = 15pF V <sub>CC</sub> = 3.3V	12 4 11	ns
f <sub>max</sub>	Maximum clock frequency		99	MHz
C <sub>I</sub>	Input capacitance		3.5	pF
C <sub>PD</sub>	Power dissipation capacitance per flip-flop	V <sub>I</sub> = GND to V <sub>CC</sub> <sup>1</sup>	23	pF

#### NOTE:

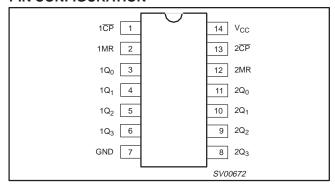
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;  $C_L$  = output load capacity in pF;

 $f_0$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;  $\Sigma$  ( $C_L \times V_{CC}^2 \times f_0$ ) = sum of the outputs.

### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	-40°C to +125°C	74LV393 N	74LV393 N	SOT27-1
14-Pin Plastic SO	-40°C to +125°C	74LV393 D	74LV393 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +125°C	74LV393 DB	74LV393 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV393 PW	74LV393PW DH	SOT402-1

### PIN CONFIGURATION



### **PIN DESCRIPTION**

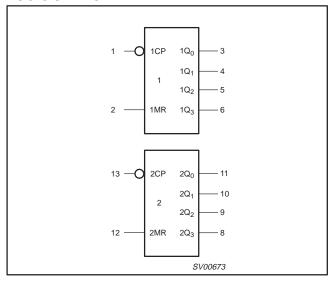
PIN NUMBER	SYMBOL	FUNCTION
1, 13	1 <u>CP</u> , 2 <u>CP</u>	Clock inputs (HIGH-to-LOW, edge-triggered)
2, 12	1MR, 2MR	Asynchronous master reset inputs (active HIGH)
3, 4, 5, 6 11, 10, 9, 8	1Q <sub>0</sub> to 1Q <sub>3</sub> 2Q <sub>0</sub> to 2Q <sub>3</sub>	Flip-flop outputs
7 GND		Ground (0V)
14	V <sub>CC</sub>	Positive supply voltage

<sup>1.</sup>  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ )

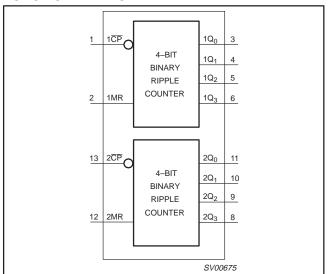
### Dual 4-bit binary ripple counter

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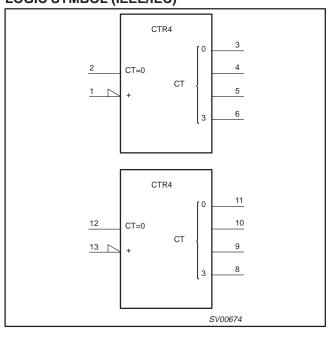
### LOGIC SYMBOL



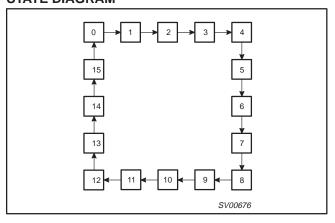
### **FUNCTIONAL DIAGRAM**



### LOGIC SYMBOL (IEEE/IEC)



### STATE DIAGRAM



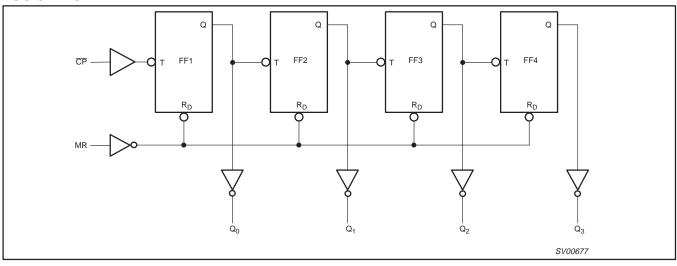
### **COUNT SEQUENCE FOR 1 COUNTER**

COUNT		OUTF	PUTS	
COUNT	$Q_0$	Q <sub>1</sub>	$Q_2$	$Q_3$
0	L	L	L	L
1	Н	L	L	L
2	L	Н	L	L
3	Н	Н	L	L
4	L	L	Н	L
5	Н	L	Н	L
6	L	Н	Н	L
7	Н	Н	Н	L
8	L	L	L	Н
9	Н	L	L	Н
10	L	Н	L	Н
11	Н	Н	L	Н
12	L	L	Н	Н
13	Н	L	Н	Н
14	L	Н	Н	Н
15	Н	Н	Н	Н

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### **LOGIC DIAGRAM**



### RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	See Note 1	1.0	3.3	3.6	V
VI	Input voltage		0	_	V <sub>CC</sub>	V
Vo	Output voltage		0	_	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.0V \text{ to } 2.0V$ $V_{CC} = 2.0V \text{ to } 2.7V$ $V_{CC} = 2.7V \text{ to } 3.6V$	-	- - -	500 200 100	ns/V

### NOTES:

### ABSOLUTE MAXIMUM RATINGS1, 2

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
±I <sub>IK</sub>	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5V$	20	mA
±I <sub>OK</sub>	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5 V$	50	mA
±ΙΟ	DC output source or sink current  – standard outputs	$-0.5V < V_O < V_{CC} + 0.5V$	25	mA
±I <sub>GND</sub> , ±I <sub>CC</sub>	DC V <sub>CC</sub> or GND current for types with – standard outputs		50	mA
T <sub>stg</sub>	Storage temperature range		–65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package  – plastic DIL  – plastic mini-pack (SO)  – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

#### NOTES

<sup>1.</sup> The LV is guaranteed to function down to  $V_{CC}$  = 1.0V (input levels GND or  $V_{CC}$ ); DC characteristics are guaranteed from  $V_{CC}$  = 1.2V to  $V_{CC}$  =3.6V.

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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### DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-4	0°C to +8	5°C	-40°C to	+125°C	UNIT
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	
		V <sub>CC</sub> = 1.2V	0.9			0.9		
$V_{IH}$	HIGH level Input voltage	V <sub>CC</sub> = 2.0V	1.4			1.4		V
	- Stange	$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	2.0			2.0		
		V <sub>CC</sub> = 1.2V			0.3		0.3	
$V_{IL}$	LOW level Input voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$ $V_{CC} = 1.2 \text{V}; V_{I} = V_{IH} \text{ or } V_{IL}; -I_{O} = 100 \mu\text{A}$			0.6		0.6	V
	lg				0.8		0.8	
	HIGH level output voltage; all outputs $V_{CC} = 2.0V$ ; $V_{I} = V_{IH}$ or $V_{IL;}$ $-I_{O} = 100\mu M$ $V_{CC} = 2.7V$ ; $V_{I} = V_{IH}$ or $V_{IL;}$ $-I_{O} = 100\mu M$ $V_{CC} = 3.0V$ ; $V_{I} = V_{IH}$ or $V_{IL;}$ $-I_{O} = 100\mu M$ HIGH level output voltage;			1.2				
			1.8	2.0		1.8		1
			2.5	2.7		2.5		1
$V_{OH}$		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	2.8	3.0		2.8		٧
	HIGH level output voltage; STANDARD outputs	$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $-I_O = 6mA$	2.40	2.82		2.20		
		$V_{CC}$ = 1.2V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0				
	LOW level output	$V_{CC}$ = 2.0V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0	0.2		0.2	
	voltage; all outputs	$V_{CC}$ = 2.7V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0	0.2		0.2	
$V_{OL}$		$V_{CC}$ = 3.0V; $V_I$ = $V_{IH}$ or $V_{IL}$ , $I_O$ = 100 $\mu$ A		0	0.2		0.2	V
	LOW level output voltage; STANDARD outputs	$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 6$ mA		0.25	0.40		0.50	
I <sub>I</sub>	Input leakage current	$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND			1.0		1.0	μА
Icc	Quiescent supply current; MSI	$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND; $I_O = 0$			20.0		160	μА
Δl <sub>CC</sub>	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$			500		850	μА

### NOTE:

<sup>1.</sup> All typical values are measured at  $T_{amb} = 25$ °C.

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### **AC CHARACTERISTICS**

 $\text{GND} = \text{OV}; \ t_\text{f} = t_\text{f} \leq \text{2.5ns}; \ C_\text{L} = \text{50pF}; \ R_\text{L} = 1 \text{K}\Omega$ 

			CONDITION			LIMITS			
SYMBOL	PARAMETER	WAVEFORM	CONDITION	_	40 to +85 °	C	-40 to	+125 °C	UNIT
			V <sub>CC</sub> (V)	MIN	TYP <sup>1</sup>	MAX	MIN	MAX	
			1.2	-	75	_	_	_	
tt	Propagation delay	Figure 1	2.0	_	26	49	_	60	ns
t <sub>PHL</sub> /t <sub>PLH</sub>	n <del>CP</del> to nQ <sub>0</sub>	rigule i	2.7	-	19	36	_	44	113
			3.0 to 3.6	-	14 <sup>2</sup>	29	_	35	
			1.2	-	25	-	_	-	
<b></b>	Propagation delay	Figure 1	2.0	-	9	17	-	20	ns
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay	Figure 1	2.7	-	6	13	-	15	115
			3.0 to 3.6	-	5 <sup>2</sup>	10	_	12	
			1.2	-	70	-	_	-	
t		Figure 2	2.0	-	24	44	_		ne
t <sub>PHL</sub>	nMR to nQn	Figure 2	2.7	-	- 18	33	-	40	115
			3.0 to 3.6	-	13 <sup>2</sup>	26	-	32	
			2.0	34	10	-	41	-	
t <sub>W</sub>	Clock pulse width HIGH or LOW	Figure 1	2.7	25	8	-	30	-	ns
	111011012011		3.0 to 3.6	20	6 <sup>2</sup>	-	24	-	
			2.0	34	12	-	41	-	
t <sub>W</sub>	Master reset pulse width; HIGH	Figure 2	2.7	25	9	-	30	-	ns
	Main, Filott		3.0 to 3.6	20	7 <sup>2</sup>	-	24	-	
			1.2	-	5	_	_	-	
	Removal time	Figure 2	2.0	5	2	_	5	-	ns
<sup>l</sup> rem	trem nMR to nCP  Maximum clock pulse frequency	Figure 2	2.7	5	2	-	5	-	115
			3.0 to 3.6	5	1 <sup>2</sup>	-	5	-	
			2.0	14	53	-	12	-	
f <sub>max</sub>		Figure 1	2.7	19	72	-	16	-	MHz
	F 550 110 quoi 10 y		3.0 to 3.6	24	90 <sup>2</sup>	_	20	-	

All typical values are measured at T<sub>amb</sub> = 25°C
 Typical values are measured at V<sub>CC</sub> = 3.3V

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#### **AC WAVEFORMS**

 $V_M$  = 1.5V at  $V_{CC} \geq$  2.7V  $V_M$  = 0.5 \*  $V_{CC}$  at  $V_{CC} <$  2.7V

 $\rm V_{OL}$  and  $\rm V_{OH}$  are the typical output voltage drop that occur with the output load.

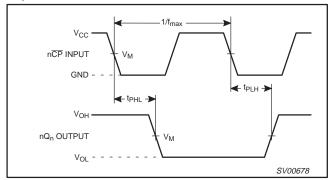


Figure 1. Clock (nCP) to output (1Qn, 2Qn) propagation delays, the clock pulse width, and the maximum clock frequency

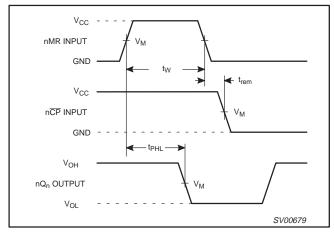


Figure 2. Master reset (nMR) pulse width, the master reset to output (Qn) propagation delays, and the master reset to clock (nCP) removal time

#### **TEST CIRCUIT**

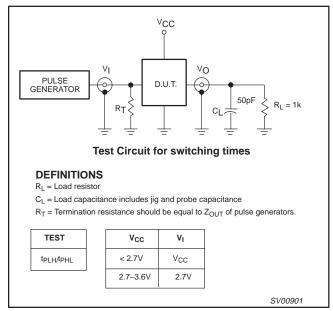


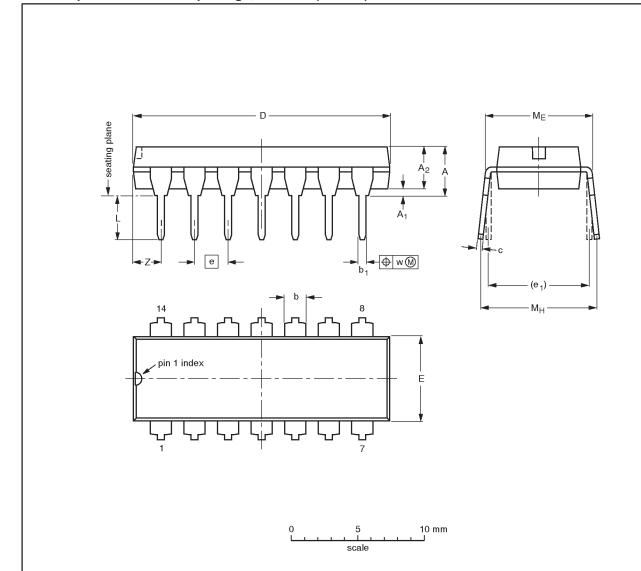
Figure 3. Load circuitry for switching times

### Dual 4-bit binary ripple counter

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### DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

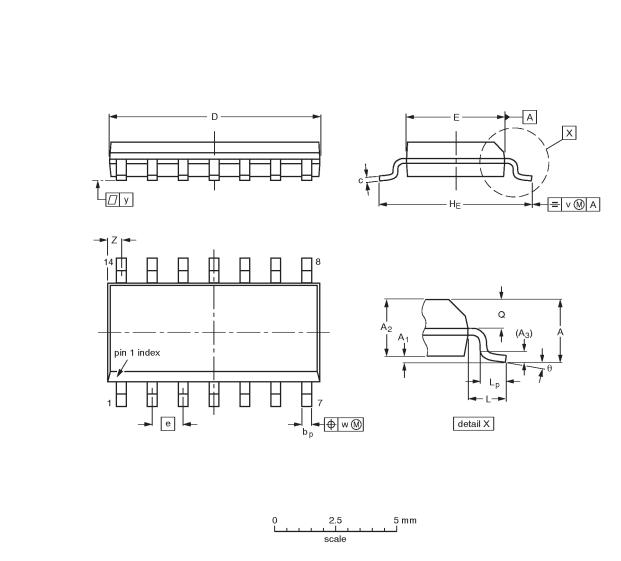
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	ı	
SOT27-1	050G04	MO-001AA			<del>92-11-17</del> 95-03-11		

### Dual 4-bit binary ripple counter

74LV393

### SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.0098 0.0039		0.01		0.0098 0.0075	0.35 0.34	0.16 0.15	0.050	0.24 0.23	0.041		0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

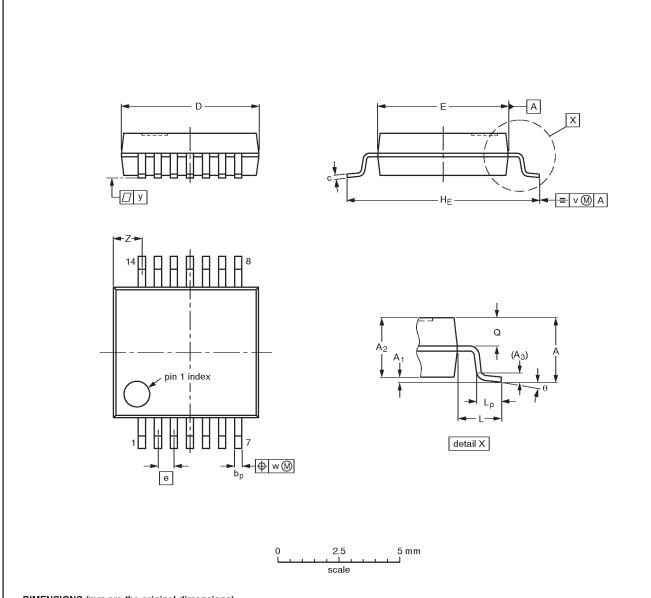
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT108-1	076E06\$	MS-012AB			<del>91-08-13</del> 95-01-23	

### Dual 4-bit binary ripple counter

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### SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

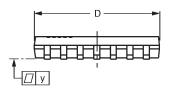
OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT337-1		MO-150AB				<del>-95-02-04</del> 96-01-18

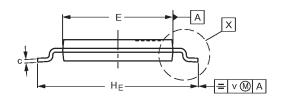
### Dual 4-bit binary ripple counter

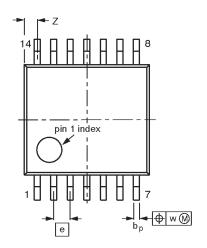
74LV393

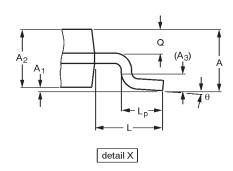
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

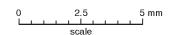
SOT402-1











### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bр	c	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		EUROPEAN	ISSUE DATE				
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	ĺ
SOT402-1		MO-153				<del>-94-07-12</del> 95-04-04	

### Dual 4-bit binary ripple counter

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	DEFINITIONS							
Data Sheet Identification	Product Status	Definition						
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.						
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philip Semiconductors reserves the right to make changes at any time without notice in order to improve desig and supply the best possible product.  This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make change at any time without notice, in order to improve design and supply the best possible product.						
Product Specification	Full Production							

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